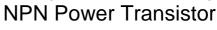
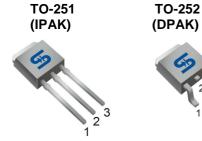




TSC5802D High Voltage Fast-Switching





AK)

1. Base 2. Collector 3. Emitter

Pin Definition:

PRODUCT SUMMARY

BV _{CEO}	450V			
BV _{CBO}	1050V			
I _C	2A			
V _{CE(SAT)}	0.5V @ I _C =0.7A, I _B =0.14A			

Collector

Emitter

Block Diagram

Base O-

High Switching Speed

Structure

Features

•

• Silicon Triple Diffused Type

High Voltage Capability

NPN Silicon Transistor

Ordering Information

Part No.	Package	Packing
TSC5802DCH C5G	TO-251	75pcs / Tube
TSC5802DCP ROG	TO-252	2.5Kpcs / 13" Reel

Note: "G" denote for Halogen Free Product

Absolute Maximum Rating ($T_A = 25^{\circ}C$, unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Collector-Base Voltage	V _{CBO}	1050	V	
Collector-Emitter Voltage @ V _{BE} =0V	V _{CES}	450	V	
Emitter-Base Voltage	V _{EBO}	15	V	
Collector Current	Ι _C	2	А	
Collector Peak Current (tp <5ms)	I _{CM}	4	А	
Base Current	Ι _Β	1.5	А	
Base Peak Current (tp <5ms)	I _{BM}	3	А	
Power Total Dissipation @ Tc=25°C	P _{DTOT}	30	W	
Maximum Operating Junction Temperature	TJ	+150	°C	
Storage Temperature Range	T _{STG}	-55 to +150	°C	

Note: Single Pulse. $P_W = 300 \text{uS}$, Duty $\leq 2\%$

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance – Junction to Case	RƏ _{JC}	4.17	°C/W
Thermal Resistance - Junction to Ambient	RƏ _{JA}	100	°C/W



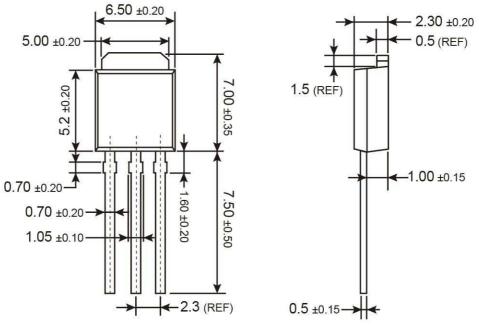
Electrical Specifications ($T_A = 25^{\circ}C$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static	·			<u> </u>		
Collector-Base Voltage	I _C =0.5mA	BV _{CBO}	1050			V
Collector-Emitter Breakdown Voltage	I _C =5mA	BV _{CEO}	450			V
Emitter-Base Breakdown Voltage	I _E =1mA	BV_{EBO}	15			V
Collector Cutoff Current	V _{CE} =400V, I _B =0	I _{CEO}		10	250	uA
Collector Cutoff Current	V _{CB} =950V, I _E =0	I _{CBO}			10	uA
Collector-Emitter Saturation Voltage	I _C =0.7A, I _B =0.14A	V _{CE(SAT)} 1			0.5	V
Collector-Emitter Saturation Voltage	I _C =2A, I _B =0.6A	V _{CE(SAT)} 2		1.5	3.0	V
Base-Emitter Saturation Voltage	I _C =2A, I _B =0.6A	V _{BE(SAT)} 1		1.0	1.6	V
DC Current Gain	$V_{CE} = 5V, I_{C} = 100 \text{mA}$	h _{FE} 1	50	70	100	
	$V_{CE} = 3V, I_{C} = 500 \text{mA}$	h _{FE} 2	18	23	50	
Diode Forward Voltage	I _C =1A	V _F			1.5	V
Resistive Load Switching Time (Rat	ings)					
Rise Time	V _{CC} =5V, I _C =0.5A,	tr			1	uS
Storage Time		t _{STG}	2.5	3	3.5	uS
Fall Time		t _f			1.2	uS

Notes: Pulsed duration =380uS, duty cycle ≤2%

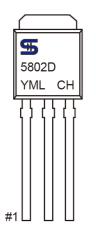


TO-251 Mechanical Drawing



Unit: Millimeters

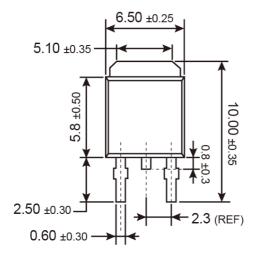
Marking Diagram

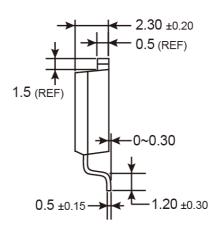


- Y = Year Code
- M = Month Code for Halogen Free Product
 (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)
- L = Lot Code



TO-252 Mechanical Drawing





Unit: Millimeters

Marking Diagram



- Y = Year Code
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